# **()** IDT.

## **ICS87158** 1-то-6, LVPECL-то-HCSL/LVCMOS ÷1, ÷2, ÷4 СLOCK GENERATOR

## **GENERAL DESCRIPTION**

The ICS87158 is a high performance 1-to-6 LVPECL-to-HCSL/LVCMOS ClockGenerator. The ICS87158 has one differential input (which can accept LVDS, LVPECL, LVHSTL, SSTL, HCSL), six differential HCSL output pairs and two complementary LVCMOS/LVTTLoutputs. The six HCSL output pairs can be individually configured for divide-by-1, 2, and 4 or high impedance by use of select pins. The two complementary LVCMOS/LVTTL outputs can be configured for divide by 2, divide by 4, high impedance, or driven low for low power operation.

The primary use of the ICS87158 is in Intel<sup>®</sup> E8870 chipsets that use Intel<sup>®</sup> Pentium 4 processors. The ICS87158 converts the differential clock from the main system clock into HCSL clocks used by Intel<sup>®</sup> Pentium 4 processors. However, the ICS87158 is a highly flexible, general purpose device that operates up to 600MHz and can be used in any situation where Differential-to-HCSL translation is required.

## FEATURES

- Six HCSL outputs
- Two LVCMOS/LVTTL outputs
- One Differential LVPECL clock input pair
- PCLK, nPCLK supports the following input types: LVDS, LVPECL, LVHSTL, SSTL, HCSL
- Maximum output frequency: 600MHz (maximum)
- Output skew: 100ps (maximum)
- Propagation delay: 4ns (maximum)
- 3.3V operating supply
- 0°C to 85°C ambient operating temperature
- Available in both standard and lead-free RoHS compliant packages
- · Industrial temperature information available upon request

## BLOCK DIAGRAM



## **PIN ASSIGNMENT**

P٧

GND [ 1 48 VDD VDD 2 47 GND_H VDD 2 47 GND_H PCLK 4 45 HOST_P1 nPCLK 5 44 HOST_N1 GND_R 6 43 GND_H VDD_M 7 42 HOST_P2 MREF 8 41 HOST_N2 nMREF 9 40 VDD_H GND_M 10 39 HOST_P3 VDD 11 38 HOST_N3 GND 12 37 GND_H				
Vdd_L □ 13 36 □ HOST_P4	VDD VDDR PCLK NPCLK GNDM MREF MREF GNDM VDDM VDDL	2 3 4 5 6 7 8 9 10 11 12 13	47 46 45 44 43 42 41 40 39 38 37 36	GND_H VDD_H HOST_P1 GND_H GND_H HOST_P2 HOST_P2 HOST_P2 HOST_P3 HOST_P3 GND_H HOST_P4
VDD_L   13   36   HOST_P4     VDD   14   35   HOST_N4     GND_L   15   34   VDD_H     SEL_T   16   33   HOST_P5     MULT_0   17   32   HOST_N5     MULT_1   18   31   GND_H     VDD_L   19   30   HOST_P6     GND_L   20   29   HOST_N6     SEL_A   21   28   VDD_H     SEL_B   22   27   IREF     SEL_U   23   26   GND_I     WR   DWN#   24   25   VDD_I	VDD_L [ VDD [ GND_L [ SEL_T [ MULT_0 [ MULT_1 [ VDD_L [ GND_L [ SEL_A [ SEL_B [ SEL_U [	13 14 15 16 17 18 19 20 21 22 23	36 35 34 33 32 31 30 29 28 27 26	HOST_P4 HOST_N4 HOST_P5 HOST_P5 GND_H HOST_P6 HOST_N6 VDD_H IREF GND_I
48-Lead TSSOP mm x 12.5mm x .92mm body package	- 48			

6.1mm x 12.5mm x .92mm body pack G Package Top View

## 48-Lead SSOP

7.5mm x 15.9mm x 2.3mm body package **F Package** Top View



#### TABLE 1. PIN DESCRIPTIONS

Number	Name	Ту	/pe	Description
1, 12	GND	Power		Power supply ground.
2, 11, 14, 48	V <sub>DD</sub>	Power		Positive supply pins.
3	V <sub>DD</sub> _R	Power		Power supply pin for differential reference clock inputs.
4	PCLK	Input		Non-inverting differential LVPECL clock input.
5	nPCLK	Input		Inverting differential LVPECL clock input.
6	GND_R	Power		Power supply ground for differential inputs.
7	V <sub>DD</sub> _M	Power		Power supply pin for MREF clock outputs.
8, 9	MREF, nMREF	Output		Single ended clocks provided as a reference clock to a memory clock driver. LVCMOS / LVTTL interface levels.
10	GND_M	Power		Power supply ground for MREF clock outputs.
13	V <sub>DD</sub> _L	Power		Power supply pin for logic input pins.
15, 20	GND_L	Power		Power supply ground for logic input pins.
16	SEL_T	Input	Pulldown	Active high input tristates all outputs. LVCMOS / LVTTL interface levels.
17	MULT_0	Input	Pulldown	The logic setting on these two pins selects the multiplying factor of the IREF reference current for the HOST pair outputs. LVCMOS / LVTTL interface levels.
18	MULT_1	Input	Pullup	The logic setting on these two pins selects the multiplying factor of the IREF reference current for the HOST pair outputs. LVCMOS / LVTTL interface levels.
19	V <sub>DD</sub> _L	Power		Power supply pin for logic input pins.
21, 22, 23	SEL_A, SEL_B, SEL_U	Input	Pulldown	Selects desired output frequencies. LVCMOS / LVTTL interface levels.
24	PWR_DWN#	Input	Pullup	Asynchronous active-low LVTTL power-down signal forces MREF outputs low, tristates HOST_N outputs, and drives HOST_P output currents to 2xIREF. LVCMOS / LVTTL interface levels.
25	V <sub>DD</sub> _I	Power		Power supply pin for IREF current reference input.
26	GND_I	Power		Power supply ground for IREF current reference input.
27	IREF	Input		A fixed precision resistor from this pin to ground provides a reference current used for differential current-mode HOST clock outputs.
28, 34, 40, 46	V <sub>DD</sub> _H	Power		Power supply pins for the differential HOST clock outputs.
29, 30	HOST_N6, HOST_P6	Output		Differential output pairs. HCSL interface levels.
31, 37, 43, 47	GND_H	Power		Power supply ground for the differential HOST clock outputs.
32, 33	HOST_N5, HOST_P5	Output		Differential output pairs. HCSL interface levels.
35, 36	HOST_N4, HOST_P4	Output		Differential output pairs. HCSL interface levels.
38, 39	HOST_N3, HOST_P3	Output		Differential output pairs. HCSL interface levels.
41, 42	HOST_N2, HOST_P2	Output		Differential output pairs. HCSL interface levels.
44, 45	HOST_N1, HOST_P1	Output		Differential output pairs. HCSL interface levels.

NOTE: Pullup and Puddown refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.



#### TABLE 2. PIN CHARACTERISTICS

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance			4		pF
R <sub>PULLUP</sub>	Input Pullup Resistor			51		kΩ
R <sub>PULLDOWN</sub>	Input Pulldown Resistor			51		kΩ

#### TABLE 3A. CONTROL INPUT FUNCTION TABLE

	In	puts						Outputs			
PWR _DWN#	SEL _T	SEL _A	SEL _B	SEL _U	HST_P1 HST_N1	HST_P2 HST_N2	HST_P3 HST_N3	HST_P4 HST_N4	HST_P5 HST_N5	HST_P6 HST_N6	MREF_P MREF_N
1	0	0	0	0	÷ 2	÷ 2	÷ 2	÷ 2	÷ 2	÷ 2	÷ 4
1	0	0	0	1	Hi Z	÷ 2	÷ 2	÷ 2	÷ 2	Hi Z	÷ 4
1	0	0	1	0	÷ 4	÷ 2	÷ 2	÷ 2	÷ 2	÷ 4	÷ 4
1	0	0	1	1	÷ 4	÷ 4	÷ 4	÷ 4	÷ 4	÷ 4	÷ 4
1	0	1	0	0	÷ 1	÷ 1	÷ 1	÷ 1	÷ 1	÷ 1	÷ 4
1	0	1	0	1	Hi Z	÷ 1	÷ 1	÷ 1	÷ 1	Hi Z	÷ 4
1	0	1	1	0	÷ 2	÷ 1	÷ 1	÷ 1	÷ 1	÷ 2	÷ 4
1	0	1	1	1	÷ 2	÷ 2	÷ 2	÷ 2	÷ 2	÷ 2	÷2
1	1	Х	Х	Х	Hi Z	Hi Z					
0	x	х	x	x	HST_P1 =2 x IREF	HST_P2 =2 x IREF	HST_P3 =2 x IREF	HST_P4 =2 x IREF	HST_P5 =2 x IREF	HST_P6 =2 x IREF	MREF_P = low
0	^	^			HST_N1 = Hi Z	HST_N2 = Hi Z	HST_N3 = Hi Z	HST_N4 = Hi Z	HST_N5 = Hi Z	HST_N6 = Hi Z	MREF_N = low

## TABLE 3B. FUNCTION TABLE

Inp	outs	Device Configurations					
MULT_0	MULT_1	Board Target Trace/Term Z	Reference R, IREF = V <sub>DD</sub> /(3*Rr)	Output Current	$V_{_{OH}} @ 50\Omega$ Environment		
0	0	50Ω	Rr = 475 1%, IREF = 2.32mA	I <sub>он</sub> = 5*IREF	0.6V		
0	1	50Ω	Rr = 475 1%, IREF = 2.32mA	I <sub>он</sub> = 6*IREF	0.7V		
1	0	50Ω	Rr = 475 1%, IREF = 2.32mA	I <sub>он</sub> = 4*IREF	0.5V		
1	1	50Ω	Rr = 475 1%, IREF = 2.32mA	I <sub>OH</sub> = 7*IREF	0.8V		



#### Absolute Maximum Ratings

Supply Voltage, $V_{\text{DD}}$	4.6V
Inputs, V <sub>I</sub>	-0.5V to $V_{_{DD}}$ + 0.5 V
Outputs, V <sub>o</sub>	-0.5V to $V_{DD}$ + 0.5V
Package Thermal Impedance, θ <sub>JA</sub> 48 Lead TSSOP 48 Lead SSOP	58.3°C/W (0 lfpm) 52.9°C/W (0 lfpm)
Storage Temperature, $T_{\rm STG}$	-65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

#### Table 4A. Power Supply DC Characteristics, $V_{DD} = 3.3V \pm 5\%$ , TA = 0°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>DD</sub>	Positive Supply Voltage		3.135	3.3	3.465	V
I <sub>DD</sub>	Power Supply Current				65	mA

#### TABLE 4B. LVCMOS / LVTTL DC CHARACTERISTICS, $V_{DD} = 3.3V \pm 5\%$ , TA = 0°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V <sub>IH</sub>	Input High Voltage			2		V <sub>DD</sub> + 0.3	mV
V <sub>IL</sub>	Input Low Voltage			-0.3		0.8	mV
		MULT_1, PWR_DWN#	$V_{DD} = V_{IN} = 3.465V$			5	μA
I <sub>IH</sub>	Input High Current	SEL_A, SEL_B, SEL_T, SEL_U, MULT_0	$V_{_{DD}} = V_{_{IN}} = 3.465V$			150	μA
		MULT_1, PWR_DWN#	$V_{_{DD}} = 3.465 \text{V}, V_{_{IN}} = 0 \text{V}$	-150			μA
I <sub>IL</sub>	Input Low Current	SEL_A, SEL_B, SEL_T, SEL_U MULT_0	$V_{_{DD}} = 3.465V, V_{_{IN}} = 0V$	-5			μA
V <sub>OH</sub>	Output High Voltage; NOTE 1			2.6			V
V <sub>OL</sub>	Output Low Voltage	; NOTE 1				0.5	V

All parameters measured at 200MHz in, 100MHz out on HOST\_XX and 50MHz out on MREF.

Current adjust set for  $V_{_{\rm OH}}$  = 0.7V. Measurements refer to HOST\_XX outputs only.

NOTE 1: Outputs terminated with 50 $\Omega$  to V<sub>DD</sub>/2. See Paramter Measurement Information Section,

"3.3V Output Load Test Circuit".

#### Table 4C. Differential DC Characteristics, $V_{DD} = 3.3V \pm 5\%$ , TA = 0°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
I <sub>IH</sub>	Input High Current	PCLK, nPCLK	$V_{DD} = V_{IN} = 3.465V$			5	μA
I	Input Low Current	PCLK, nPCLK	V <sub>DD</sub> = 3.465V, V <sub>IN</sub> = 0V	-5			μA
V <sub>PP</sub>	Peak-to-Peak Input	Voltage		0.15		1.3	V
V <sub>CMR</sub>	Common Mode Inpu	it Voltage; NOTE 1, 2		GND + 0.5		V <sub>DD</sub> - 0.85	V

All parameters measured at 200MHz in, 100MHz out on HOST\_XX and 50MHz out on MREF.

Current adjust set for  $V_{OH} = 0.7V$ . Measurements refer to HOST\_XX outputs only.

NOTE 1: Common mode voltage is defined as V<sub>III</sub>.

NOTE 2: For single ended applications, the maximum input voltage for PCLK, nPCLK is V<sub>np</sub> + 0.3V.



#### TABLE 4D. HCSL DC CHARACTERISTICS, $V_{DD} = 3.3V \pm 5\%$ , TA = 0°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
I <sub>он</sub>	Output Current		12.9		14.9	mA
V <sub>OH</sub>	Output High Voltage	RREF = 475Ω, RLOAD = 50Ω $I_{OH} = 6^{*}IREF$		0.7		V
V <sub>ol</sub>	Output Low Voltage	$\label{eq:REF} \begin{array}{l} RREF = 475\Omega, \ RLOAD = 50\Omega \\ I_{OH} = 6^*IREF \end{array}$		0.03		V
I <sub>oz</sub>	High Impedance Leakage Current		-10		10	μA
V <sub>ox</sub>	Output Crossover Voltage		280		430	mV

All parameters measured at 200MHz in, 100MHz out on HOST\_XX and 50MHz out on MREF.

Current adjust set for  $V_{OH} = 0.7V$ . Measurements refer to HOST\_XX outputs only.

## Table 5A. HCSL AC Characteristics, $V_{_{DD}}$ = 3.3V±5%, Ta = 0°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f <sub>MAX</sub>	Output Frequency				600	MHz
t <sub>PD</sub>	Propagation Delay; NOTE 1			3.7	4.0	ns
<i>t</i> sk(o)	Output Skew; NOTE 2, 4, 5			60	100	ps
<i>t</i> sk(pp)	Part-to-Part Skew; NOTE 3, 5				500	ps
<i>t</i> jit(cc)	Cycle-to-Cycle Jitter				150	ps
t <sub>R</sub>	Output Rise Time	20% to 80%	175		700	ps
t <sub>F</sub>	Output Fall Time	20% to 80%	175		700	ps
odc	Output Duty Cycle		48		52	%

All parameters measured at 200MHz in, 100MHz out on HOST\_XX and 50MHz out on MREF.

Current adjust set for  $\rm V_{_{OH}}$  = 0.7V. Measurements refer to HOST\_XX outputs only.

NOTE 1: Measured from the differential input crossing point to the differential output crossing point.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured at the output differential cross points.

NOTE 3: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at the differential cross points. NOTE 4: Maximum value calculated at  $+3\sigma$  from typical.

NOTE 5: This parameter is defined in accordance with JEDEC Standard 65.

#### TABLE 5B. LVCMOS / LVTTL AC Characteristics, $V_{DD} = 3.3V \pm 5\%$ , TA = 0°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f <sub>MAX</sub>	Output Frequency				300	MHz
<i>t</i> jit(cc)	Cycle-to-Cycle Jitter	$C_{L} = 10 pF/30 pF$			150	ps
t <sub>R</sub> Output Rise Time	0.4V to 2.4V, $C_{L} = 10 pF$	0.4			ns	
	Output Rise Time	0.4V to 2.4V, C <sub>L</sub> = 30pF			1.8	ns
+	Output Fall Time	0.4V to 2.4V, $C_{L} = 10 pF$	0.4			ns
t <sub>F</sub>	Output Fall Time	0.4V to 2.4V, C <sub>L</sub> = 30pF			2	ns
odc	Output Duty Cycle	$C_{L} = 10 pF/30 pF$	48		52	%

All parameters measured at 200MHz in, 100MHz out on HOST\_XX and 50MHz out on MREF. Current adjust set for  $V_{OH} = 0.7V$ . Measurements refer to MREF outputs only.



# PARAMETER MEASUREMENT INFORMATION









# **APPLICATION** INFORMATION

#### WIRING THE DIFFERENTIAL INPUT TO ACCEPT SINGLE ENDED LEVELS

*Figure 1* shows how the differential input can be wired to accept single ended levels. The reference voltage  $V_REF = V_{DD}/2$  is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio

of R1 and R2 might need to be adjusted to position the V\_REF in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and  $V_{DD}$ = 3.3V, V\_REF should be 1.25V and R2/R1 = 0.609.



## **RECOMMENDATIONS FOR UNUSED INPUT AND OUTPUT PINS**

#### **INPUTS:**

#### PCLK/nPCLK INPUT:

For applications not requiring the use of a differential input, both the PCLK and nPCLK pins can be left floating. Though not required, but for additional protection, a  $1k\Omega$  resistor can be tied from PCLK to ground.

#### LVCMOS CONTROL PINS:

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A  $1k\Omega$  resistor can be used.

## OUTPUTS:

#### LVCMOS OUTPUT:

All unused LVCMOS outputs can be left floating. There should be no trace attached.

#### HCSL OUTPUT

All unused HCSL outputs can be left floating. We recommend that there is no trace attached. Both sides of the differential output pair should either be left floating or terminated.



## LVPECL CLOCK INPUT INTERFACE

The PCLK /nPCLK accepts LVPECL, CML, SSTL and other differential signals. Both V<sub>SWING</sub> and V<sub>OH</sub> must meet the V<sub>PP</sub> and V<sub>CMR</sub> input requirements. *Figures 2A to 2F* show interface examples for the PCLK/nPCLK input driven by the most common driver types. The input interfaces suggested here

3.3V CML Zo = 50 Ohm T Zo = 50 Ohm T Zo = 50 Ohm R1 R2 50 PCLK HIPerClockS PCLK PCLK

FIGURE 2A. PCLK/nPCLK INPUT DRIVEN BY AN OPEN COLLECTOR CML DRIVER



FIGURE 2C. PCLK/nPCLK INPUT DRIVEN BY A 3.3V LVPECL DRIVER



FIGURE 2E. PCLK/nPCLK INPUT DRIVEN BY AN SSTL DRIVER

are examples only. If the driver is from another vendor, use their termination recommendation. Please consult with the vendor of the driver component to confirm the driver termination requirements.



FIGURE 2B. PCLK/nPCLK INPUT DRIVEN BY A BUILT-IN PULLUP CML DRIVER



FIGURE 2D. PCLK/nPCLK INPUT DRIVEN BY A 3.3V LVPECL DRIVER WITH AC COUPLE



FIGURE 2F. PCLK/nPCLK INPUT DRIVEN BY A 3.3V LVDS DRIVER



## SCHEMATIC EXAMPLE

*Figure 3* shows an example of the ICS87158 LVPECL to HCSL Clock Generator schematic.

In this example, the ICS87158 is configured as follows:

$$\label{eq:pwr_DWN} \begin{split} & \mathsf{PWR}\_\mathsf{DWN} \# = 1 \\ & \mathsf{Mult}\_[1:0] = 10, \, \mathsf{Rref} = 475\Omega, \, \mathsf{IREF} = 2.32\mathsf{mA}, \, \mathsf{I}_{\mathsf{OH}} = 6^*\mathsf{IREF} \\ & \mathsf{SEL}\_[\mathsf{A},\mathsf{B},\mathsf{U}] = 000, \, \mathsf{MREF} = \mathsf{PECL} \div 4, \, \mathsf{all} \, \mathsf{HOST} \, \mathsf{output} = \mathsf{PECL} \div 2 \\ & \mathsf{SEL}\_\mathsf{T} = 0, \, \mathsf{Output} \, \mathsf{Enable} \end{split}$$



FIGURE 3. ICS87158 SCHEMATIC LAYOUT



## **Power and Ground**

This section provides a layout guide related to power, ground and placement of bypass capacitors for a highspeed digital IC. This layout guide is a general recommendation. The actual board design will depend on the component types being used, the board density and cost constraints. The description assumes that the board has clean power and ground planes. The principle is to minimize the ESR between the clean power/ground plane and the IC power/ground pin.

A low ESR bypass capacitor should be used on each power pin. The value of bypass capacitors ranges from 0.01uF to 0.1uF. The bypass capacitors should be located as close to the power pin as possible. It is preferable to locate the bypass capacitor on the same side as the IC. *Figure 4* shows suggested capacitor placement. Placing the bypass capacitor on the same side as IC allows the capacitor to have direct contact with the IC power pin. This can avoid any vias between the bypass capacitor and the IC power pins.

The vias should be place at the Power/Ground pads. There should be minimum one via per pin. Increase the number of vias from the Power/Ground pads to Power/Ground planes can improve the conductivity.



FIGURE 4. RECOMMENDED LAYOUT OF BYPASS CAPACITOR PLACEMENT



## LOGIC CONTROL INPUT

The logic input control signals are 3.3V LVCMOS compatible. The logic control input contains ESD diodes and either pull-up or pull-down resistor as shown in *Figure 5*. The data sheet provides pull-up or pull-down information for each input pin. Leaving the input floating will set the control logic to default setting. To set logic high, the input pin connected directly to  $V_{DD}$ . To set logic low, the control input connect directly to ground. For control signal source from the driver that has different power supply, a series current resistor of greater than 100 Ohm is required for random power on sequence.





## **HCSL Driver Termination**

The HCSL is a differential constant current source driver. The output current is set by control pins MULT\_[1:0] and the value of resistor Rref.

In the characteristic impedance of 50 Ohm environment, the match load 50 Ohm resistors R4 and R5 are terminated at the receiving end of the transmission line. The 33 Ohm series resistor R6 and R7 should be located as close to the driver pins as possible. For the clock traces that required very low skew should have equal length.

Other general rules of high-speed digital design also should be followed. Some check points are listed as follows:

- Avoid sharp angles on the clock trace. Sharp angle turn causes the characteristic impedance change on the transmission lines.
- Keep the clock trace on same layer. Whenever possible, avoid any vias on the middle clock traces. Any via on middle the trace can affect the trace characteristic impedance and hence degrade signal quality.
- There should be sufficient space between the clock traces that have different frequencies to avoid cross talk.
- No other signal trace is routed between the clock trace pair.
- Transmission line should not be routed across the split plane on the adjacent layer.



# **R**ELIABILITY INFORMATION

## TABLE 6A. $\boldsymbol{\theta}_{JA} \text{vs.}$ Air Flow Table For 48 Lead TSSOP Package

θ <sub>JA</sub> by Velocity (Linear Feet per Minute)			
	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	82.6°C/W	70.3°C/W	63.7°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	58.3°C/W	52.3°C/W	49.9°C/W

## TABLE 6B. $\theta_{JA} vs.$ Air Flow Table For 48 Lead SSOP Package

θ <sub>JA</sub> by Velocity (Linear Feet per Minute)				
	0	200	500	
Multi-Layer PCB, JEDEC Standard Test Boards	52.9°C/W	46.0°C/W	42.0°C/W	

#### TRANSISTOR COUNT

The transistor count for ICS87158 is: 2631



#### PACKAGE OUTLINE - G SUFFIX FOR 48 LEAD TSSOP

#### PACKAGE OUTLINE - F SUFFIX FOR 48 LEAD SSOP





#### TABLE 6A. PACKAGE DIMENSIONS

SYMBOL	Millimeters		
STMBOL	Minimum	Maximum	
Ν	4	8	
A		1.20	
A1	0.05	0.15	
A2	0.80	1.05	
b	0.17	0.27	
с	0.09	0.20	
D	12.40	12.60	
E	8.10 BASIC		
E1	6.00	6.20	
е	0.50 BASIC		
L	0.45	0.75	
α	0°	8°	
aaa		0.10	

Reference Document: JEDEC Publication 95, MO-153

#### TABLE 6B. PACKAGE DIMENSIONS

SYMBOL	Millimeters		
STMBOL	Minimum	Maximum	
N	4	.8	
А	2.41	2.80	
A1	0.20	0.40	
b	0.20	0.34	
С	0.13	0.25	
D	15.75	16.00	
E	10.03	10.68	
E1	7.40	7.60	
е	0.635 BASIC		
h	0.38	0.64	
L	0.50	1.02	
α	0°	8°	

Reference Document: JEDEC Publication 95, MO-118



#### TABLE 7. ORDERING INFORMATION

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
87158AG	ICS87158AG	48 Lead TSSOP	Tube	0°C to 85°C
87158AGT	ICS87158AG	48 Lead TSSOP	1000 Tape & Reel	0°C to 85°C
87158AGLF	ICS87158AGLF	48 Lead "Lead-Free" TSSOP	Tube	0°C to 85°C
87158AGLFT	ICS87158AGLF	48 Lead "Lead-Free" TSSOP	1000 Tape & Reel	0°C to 85°C
87158AF	ICS87158AF	48 Lead SSOP	Tube	0°C to 85°C
87158AFT	ICS87158AF	48 Lead SSOP	1000 Tape & Reel	0°C to 85°C
87158AFLF	ICS87158AFLF	48 Lead "Lead-Free" SSOP	Tube	0°C to 85°C
87158AFLFT	ICS87158AFLF	48 Lead "Lead-Free" SSOP	1000 Tape & Reel	0°C to 85°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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	REVISION HISTORY SHEET				
Rev	Table Page Description of Change		Date		
		1	Pin Assignment - corrected typo error for Pin 4 and 5.		
		6	Corrected 3.3V LVCMOS Output Load Test Circuit Diagram.	1/15/00	
A			Updated Single Ended Signal Driving Differential Input Diagram.	1/15/03	
		8	Updated format.		
	T2	3	Pin Characteristics Table - changed C <sub>IN</sub> 4pF max. to 4pF typical.		
В	T4A	4	Power Supply Table - changed I DD 48mA typical to 65mA max.	6/24/04	
		9	Updated LVPECL Clock Input Interface section.		
в		1	Added Lead-Free bullet to Features section.	7/8/04	
В	T7	15	Added Lead-Free part number to Ordering Information table.	770/04	
в		8	Added Recommendations for Unused Input and Output Pins.	1/17/06	
P T7		15	Ordering Information Table - added TSSOP Lead-Free part number and note.	1/17/06	
в	T7	15	Ordering Information Table - added TSSOP Lead-Free marking, and corrected	3/10/06	
	10	TSSOP T&R count.	0/10/00		
			Updated datasheet's header/footer with IDT from ICS.		
С	T7	15	Removed ICS prefix from Part/Order Number column.	7/25/10	
		17	Added Contact Page.		



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